

High-reliability discrete products and engineering services since 1977

## MAC6401 SERIES

### BIDIRECTIONAL TRIODE THYRISTORS

### **FEATURES**

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit	
Repetitive peak off-stage voltage, gate open				
$(T_J = -65 \text{ to } +100^{\circ}\text{C})$				
MAC6401B	$V_{DRM}$	200	Volts	
MAC6401D	V DRM	400	VOILS	
MAC6401M		600		
MAC6401N		800		
<b>RMS on-state current</b> (conduction angle = $360^{\circ}$ , $T_C \le 65^{\circ}$ C)	I <sub>T(RMS)</sub>	30	Amps	
Peak non-repetitive surge current (One Cycle, 60Hz)	I <sub>TSM</sub>	300	Amps	
Circuit fusing considerations	I <sup>2</sup> t		A <sup>2</sup> s	
(T <sub>J</sub> = -65 to +100°C, t = 1.25 to 10ms)	I t	450	AS	
<b>Peak gate power</b> (pulse width = $1.0 \mu s$ )	P <sub>GM</sub>	40	Watts	
Average gate power	P <sub>G(AV)</sub>	0.75	Watts	
Peak gate current (pulse width ≤ 1.0μs)	I <sub>GM</sub>	2	Amps	
Operating junction temperature range	Tı	-65 to +100	°C	
Storage temperature range	T <sub>stg</sub>	-65 to +150	°C	
Stud torque		30	In. lb.	

### THERMAL CHARACTERISTICS

Characteristics	Symbol	Max	Unit
Thermal resistance, junction to case	R <sub>eJC</sub>	0.9	°C/W

### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> = 25°C and either polarity of MT2 to MT1 voltage, unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak off state current $(V_D = V_{DRM}, \text{ gate open, } T_J = 100^{\circ}\text{C}$	I <sub>DRM</sub>	-	-	4	mA
Peak on-state voltage (either direction) (I <sub>TM</sub> = 100A peak)	V <sub>TM</sub>	-	2.1	2.5	Volts
DC gate trigger current (continuous dc) $(V_D=12V,R_L=30\Omega)$ $MT2(+),G(+);MT2(-),G(-)$ $MT2(+),G(-);MT2(-),G(+)$	I <sub>GT</sub>	-	20 35	50 80	mA
<b>DC gate trigger voltage</b> (continuous dc), all trigger modes $(V_D=12V,R_L=30\Omega)\\ (V_D=RatedV_{DRM},R_L=125\Omega,T_C=100^{\circ}C)$	V <sub>GT</sub>	0.2	1.35 -	2.5	Volts
<b>Holding current</b> $(V_D = 12V, \text{ gate open, } I_T = 150\text{mA})$	I <sub>H</sub>	-	-	60	mA
Gate controlled turn on time $(V_D = \text{Rated } V_{DRM}, I_{TM} = 45 \text{A}, I_{GT} = 200 \text{mA}, \text{rise time} = 0.1 \mu\text{s})$	t <sub>gt</sub>	-	1.7	3	μs



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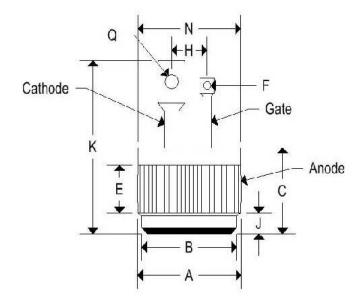
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Critical rate of rise of commutating voltage (commutating di/dt = 16A/ms, gate unenergized, $V_D$ = Rated $V_{DRM}$ , $I_{T(RMS)}$ = 30A, $T_C$ = rated value from figure 1)	dv/dt(c)	3	20	-	V/µs
Critical rate of rise of off-state voltage $(V_D = Rated\ V_{DRM},\ gate\ open,\ exponential\ waveform,\ T_C = 100°C)$ MAC6401B MAC6401D MAC6401M	dv/dt	40 25 20	-	-	V/μs

### **MECHANICAL CHARACTERISTICS**

Case	Digi PF1
Marking	Alpha-numeric



	DIGI PF1				
	Inc	Inches		neters	
	Min	Max	Min	Max	
Α	0.501	0.505	12.730	12.830	
F	12.	0.160	12.	4.060	
G	0.085	0.095	2.160	2.410	
Н	0.060	0.070	1.520	1.780	
J	0.300	0.350	7.620	8.890	
K	-	1.050	14	26.670	
L		0.670	(=)	17.020	
Q	0.055	0.085	1.400	2.160	

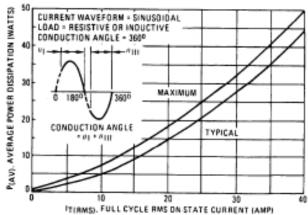


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### FIGURE 2 - RMS CURRENT DERATING

